

/ Descriptions

KF 50) CD E GE Silicon NPN transistor in a TO-92LM Plastic Package.

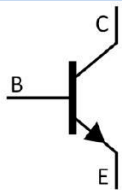
/ Features

) J80* +
High P_C, low collector saturation voltage, complementary pair with 2SA934.

/ Applications

() N
1 2W low frequency amplifiers.

/ Equivalent Circuit



/ Pinning

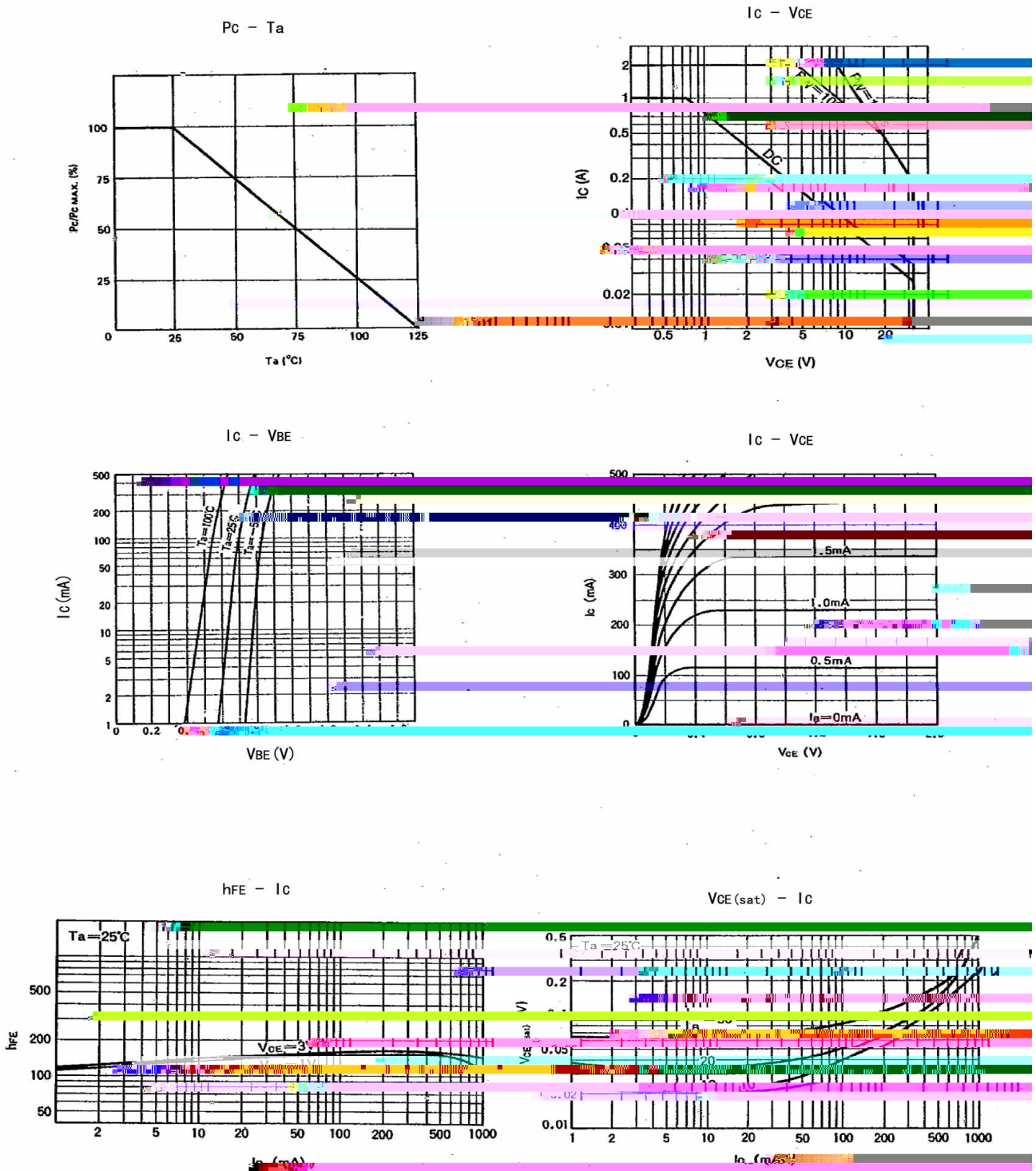


PIN1 Base PIN 2 Collector PIN 3 Emitter

/ h_{FE} Classifications & Marking

h _{FE} Classifications Symbol	P	Q	R
h _{FE} Range	82 180	120 270	180 390

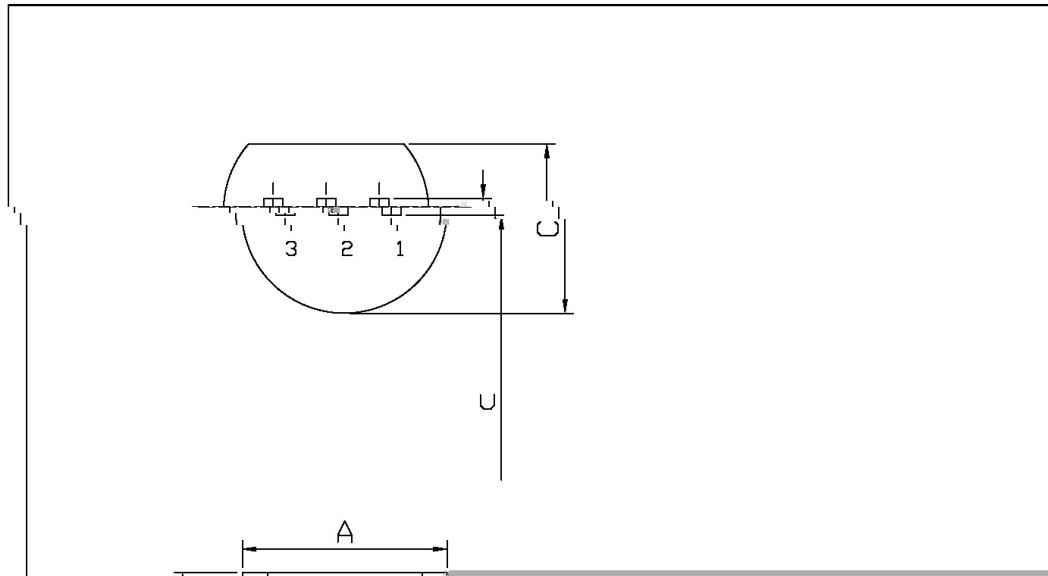
/ Electrical Characteristic Curve



/ Package Dimensions

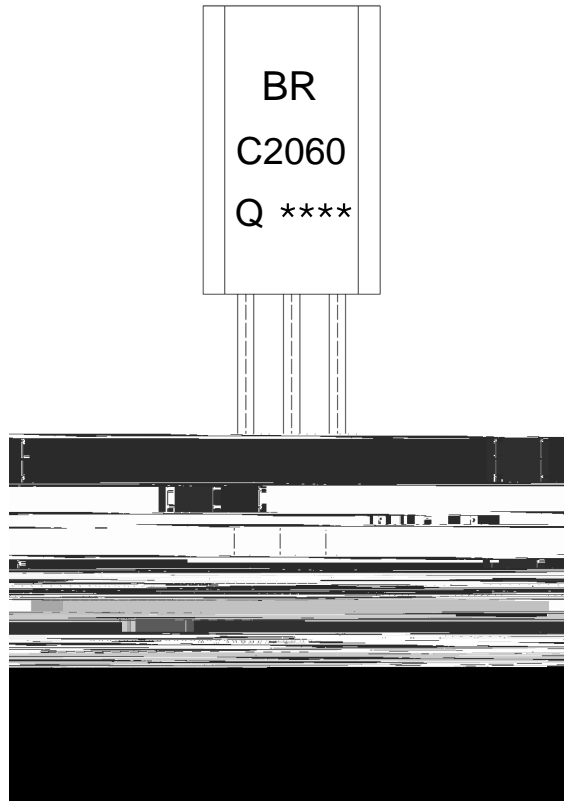
TO-92LM

Unit: mm



Symbol	Dimensions In Millimeters	
	Min	Max
A	1.47	2.0
C	5.0	5.5
U	2.0	2.5

/ Marking Instructions

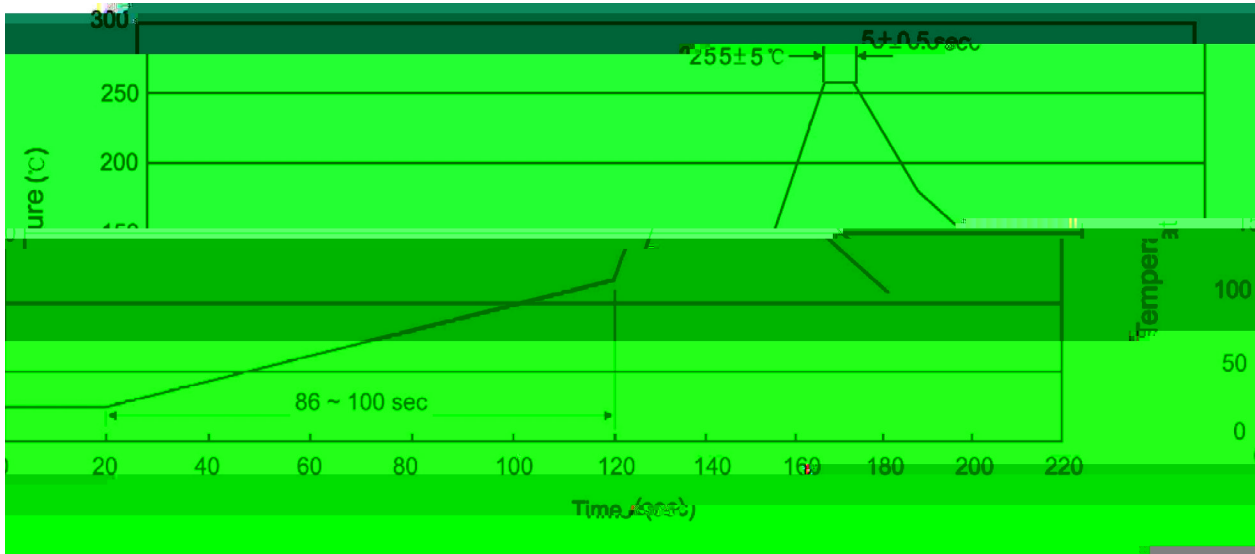


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H1
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Note:

- BR: Company Code.
- C2060: Product Type.
- Q: h_{FE} Classifications Symbol
- ****: Lot No. Code, code change with Lot No.

() / Temperature Profile for Dip Soldering(Pb-Free)



Note:

- | | | | | | |
|---|--------|-----|------------|----------|---|
| 1 | 25 | 150 | 60 | 90sec; | 1.Preheating:25~150 , Time:60~90sec. |
| 2 | 255..5 | | 5..0.5sec; | | 2.Peak Temp.:255..5 , Duration:5..0.5sec. |
| 3 | | | 2 | 10 /sec. | 3. Cooling Speed: 2~10 /sec. |

/ Resistance to Soldering Heat Test Conditions

270..5 10...1 sec. Temp.:270±5 Time:10±1 sec

/ Packaging SPEC.

/ BULK

Package Type 封装形式	Units 包装数量					Dimension 包装尺寸 (unit: mm3)		
	Units/Bag 只/袋	Bags/Inner Box 袋/盒	Units/Inner Box 只/盒	Inner Boxes/Outer Box 盒/箱	Units/Outer Box 只/箱	Bag 袋	Inner Box 盒	Outer Box 箱
TO-92LM	1,000	8	8,000	5	40,000	135×190	237×172×102	560×245×195

/ AMMO

Package Type 封装形式	Units 包装数量					Dimension 包装尺寸 (unit: mm3)	
	Units/tape 只/纸带	Tape/Inner Box 纸带/盒	Rows/Inner Box 纸带层/盒	Inner Boxes/Outer Box 盒/箱	Units/Outer Box 只/箱	Inner Box 盒	Outer Box 箱
TO-92LM	2,500	1	100	10	25,000	328×230×42	小箱 480×346×235 大箱 547×407×268

/ Notices